

STGB6NC60H

N-channel 600V - 7A - D²PAK Very fast PowerMESH™ IGBT

General features

| Туре | V _{CES} | V _{CE(sat)} max @25°C | I _C @100°C |
|------------|------------------|-----------------------------------|--------------------------|
| STGB6NC60H | 600V | <2.5V | 7A |

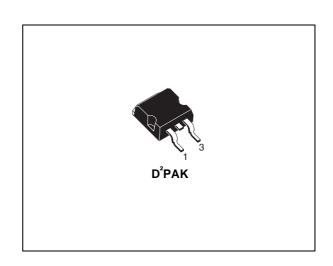
- Low on voltage drop (V_{cesat})
- Low C_{RES} / C_{IES} ratio (no cross-conduction susceptibility)
- Very soft ultra fast recovery antiparallel diode
- High frequency operation



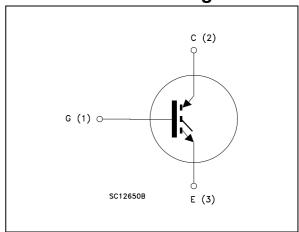
Using the latest high voltage technology based on a patented strip layout, STMicroelectronics has designed an advaced family of IGBTs, the PowerMESHTM IGBTs, with outstanding performances. The suffix "H" identifies a family optimized for high frequency application in order to achieve very high switching performances (reduced tfall) mantaining a low voltage drop.

Applications

- High frequency inverters
- SMPS and PFC in both hard switch and resonant topologies
- Motor drivers



Internal schematic diagram



Order codes

| Part number | Marking | Marking Package | |
|--------------|----------|--------------------|-------------|
| STGB6NC60HT4 | GB6NC60H | D ² PAK | Tape & reel |

Contents STGB6NC60H

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STGB6NC60H Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|--------------------------------|--|-------------|------|
| V _{CES} | Collector-emitter voltage (V _{GS} = 0) | 600 | V |
| I _C ⁽¹⁾ | Collector current (continuous) at T _C = 25°C | 15 | Α |
| I _C ⁽¹⁾ | Collector current (continuous) at T _C = 100°C | 7 | Α |
| I _{CM} ⁽²⁾ | Collector current (pulsed) | 21 | Α |
| V _{GE} | Gate-emitter voltage | ±20 | V |
| P _{TOT} | Total dissipation at T _C = 25°C | 56 | W |
| T _{stg} | Storage temperature | - 55 to 150 | °C |
| T _j | Operating junction temperature | | J |
| T _I | Maximum lead temperature for soldering purpose (for 10sec. 1.6 mm from case) | 300 | °C |

^{1.} Calculated according to the iterative formula::

$$I_{C}(T_{C}) = \frac{T_{JMAX} - T_{C}}{R_{THJ-C} \times V_{CESAT(MAX)}(T_{C}, I_{C})}$$

2. Pulse width limited by max junction temperature

Table 2. Thermal resistance

| Symbol | Parameter | Value | Unit |
|-----------|---|-------|------|
| Rthj-case | Thermal resistance junction-case max | 2 | °C/W |
| Rthj-amb | Thermal resistance junction-ambient max | 62.5 | °C/W |

Electrical characteristics STGB6NC60H

2 Electrical characteristics

(T_{CASE} =25°C unless otherwise specified)

Table 3. Static

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|----------------------|--|---|------|------------|---------|----------|
| V _{BR(CES)} | Collector-emitter breakdown voltage | $I_C = 1$ mA, $V_{GE} = 0$ | 600 | | | ٧ |
| V _{CE(sat)} | Collector-emitter saturation voltage | $V_{GE} = 15V, I_{C} = 3A$ $V_{GE} = 15V, I_{C} = 3A, T_{C} = 125^{\circ}C$ | | 1.9 1.7 | 2.5 | V V |
| V _{GE(th)} | Gate threshold voltage | $V_{CE} = V_{GE}, I_{C} = 250 \mu A$ | 3.75 | | 5.75 | V |
| I _{CES} | Collector cut-off current (V _{GE} = 0) | V_{CE} = Max rating, T_{C} = 25°C V_{CE} = Max rating, T_{C} = 125°C | | | 10 1 | μA mA |
| I _{GES} | Gate-emitter leakage current (V _{CE} = 0) | V _{GE} = ±20V , V _{CE} = 0 | | | ±100 | nA |
| 9 _{fs} | Forward transconductance | $V_{CE} = 15V_{,} I_{C} = 3A$ | | 3 | | S |

Table 4. Dynamic

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|--|---|--|------|--------------------|------|----------------|
| C _{ies} C _{oes} C _{res} | Input capacitance Output capacitance Reverse transfer capacitance | V _{CE} = 25V, f = 1MHz, V _{GE} = 0 | | 205 32 5.5 | | pF pF pF |
| Q _g Q _{ge} Q _{gc} | Total gate charge Gate-emitter charge Gate-collector charge | V_{CE} = 390V, I_{C} = 3A, V_{GE} = 15V, (see Figure 16) | | 13.6 3.4 5.1 | | nC nC nC |
| I _{CL} | Turn-off SOA minimum current | $V_{clamp} = 390V, Tj = 150$ °C, $R_G = 10\Omega \ V_{GE} = 15V$ | | 19 | | Α |

Table 5. Switching on/off (inductive load)

| Symbol | Parameter Test conditions | | Min. | Тур. | Max. | Unit |
|---|---|--|------|------------------|------|------------------|
| t _{d(on)} t _r (di/dt) _{on} | Turn-on delay time Current rise time Turn-on current slope | V_{CC} = 390V, I_{C} = 3A R_{G} = 10 Ω V_{GE} = 15V, T_{J} = 25°C (see Figure 17) | | 12 5 612 | | ns ns A/µs |
| t _{d(on)} t _r (di/dt) _{on} | Turn-on delay time Current rise time Turn-on current slope | V_{CC} = 390V, I_{C} = 3A R_{G} = 10 Ω V_{GE} = 15V, T_{J} =125°C (see Figure 17) | | 13 4.3 560 | | ns ns A/µs |
| t _r (V _{off}) t _d (_{off}) t _f | Off voltage rise time Turn-off delay time Current fall time | V_{CC} = 390V, I_{C} = 3A, R_{GE} = 10 Ω , V_{GE} = 15V, T_{J} = 25°C (see Figure 17) | | 40 76 100 | | ns ns ns |
| $t_{r}(V_{off})$ $t_{d}(_{off})$ t_{f} | Off voltage rise time Turn-off delay time Current fall time | V_{CC} = 390V, I_{C} = 3A, R_{GE} = 10 Ω , V_{GE} =15V, Tj = 125°C (see Figure 17) | | 60 98 124 | | ns ns ns |

Table 6. Switching energy (inductive load)

| Symbol | Parameter | Test condictions | Min. | Тур. | Max. | Unit |
|--|---|---|------|-----------------|------|----------------|
| E _{on} ⁽¹⁾ E _{off} ⁽²⁾ E _{ts} | Turn-on switching losses Turn-off switching losses Total switching losses | V_{CC} = 390V, I_{C} = 3A R_{G} = 10 Ω V_{GE} =15V, T_{J} =25°C (see Figure 17) | | 20 68 88 | | μJ μJ μJ |
| E _{on} ⁽¹⁾ E _{off} ⁽²⁾ E _{ts} | Turn-on switching losses Turn-off switching losses Total switching losses | V_{CC} = 390V, I_{C} = 3A R_{G} = 10 Ω V_{GE} = 15V, T_{J} = 125°C (see Figure 17) | | 37 93 130 | | μJ μJ μJ |

Eon is the tun-on losses when a typical diode is used in the test circuit in figure 17. If the IGBT is offered in a package with a co-pak diode, the co-pack diode is used as external diode. IGBTs & Diode are at the same temperature (25°C and 125°C)

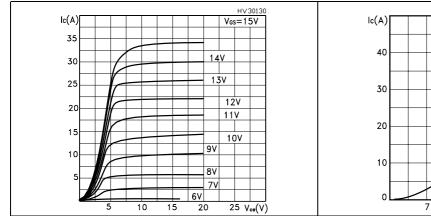
^{2.} Turn-off losses include also the tail of the collector current

Electrical characteristics STGB6NC60H

2.1 Electrical characteristics (curves)

Figure 1. Output characterisics

Figure 2. Transfer characteristics



Ic(A)

40

30

VcE = 15V

10

7

9

11

13 VGE(V)

Figure 3. Transconductance

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Figure 4. Collector-emitter on voltage vs temperature

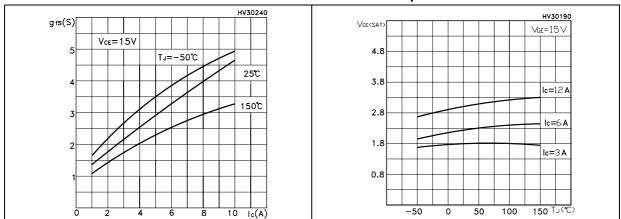


Figure 5. Gate charge vs gate-source voltage Figure 6. Capacitance variations

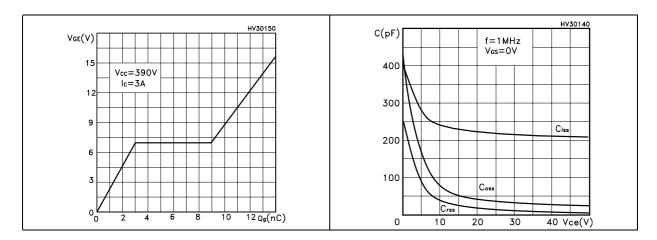


Figure 7. Normalized gate threshold voltage Figure 8. Collector-emitter on voltage vs vs temperature collector current

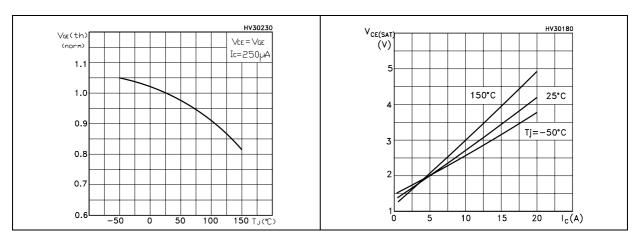


Figure 9. Normalized breakdown voltage vs Figure 10. Switching losses vs temperature temperature

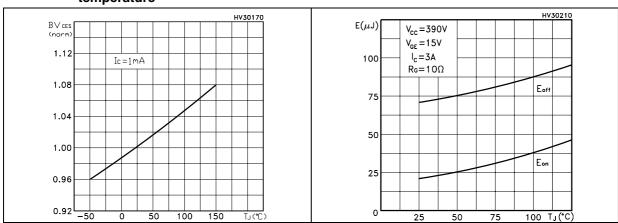
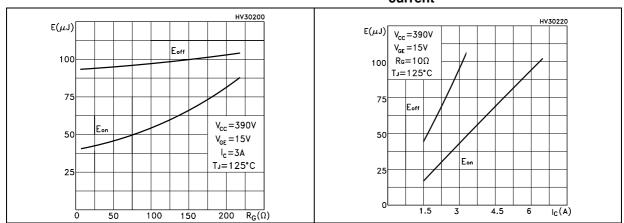


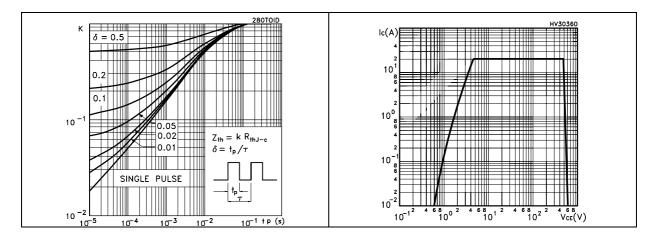
Figure 11. Switching losses vs gate resistance Figure 12. Switching losses vs collector current



Electrical characteristics STGB6NC60H

Figure 13. Thermal impedance

Figure 14. Turn-off SOA



STGB6NC60H Test circuit

3 Test circuit

Figure 15. Test circuit for inductive load switching

Figure 16. Gate charge test circuit

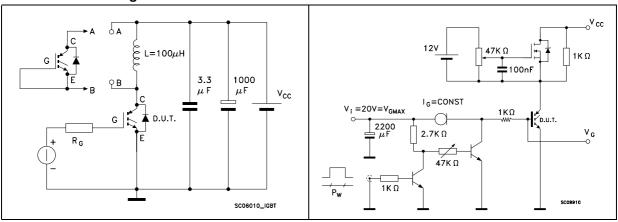
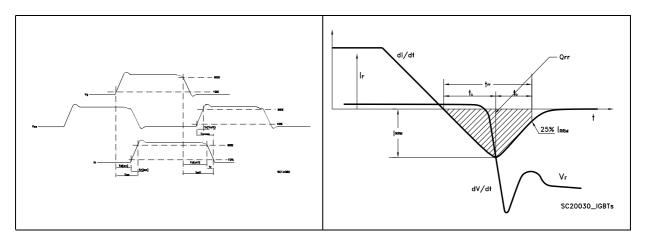


Figure 17. Switching waveform

Figure 18. Diode recovery time waveform



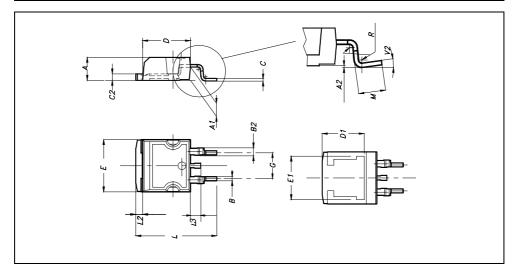
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4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

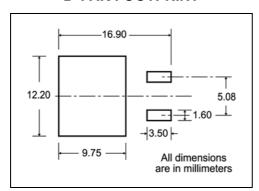
D²PAK MECHANICAL DATA

| DIM. | | mm. | | | inch | |
|------|------|-----|-------|-------|-------|-------|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. |
| Α | 4.4 | | 4.6 | 0.173 | | 0.181 |
| A1 | 2.49 | | 2.69 | 0.098 | | 0.106 |
| A2 | 0.03 | | 0.23 | 0.001 | | 0.009 |
| В | 0.7 | | 0.93 | 0.027 | | 0.036 |
| B2 | 1.14 | | 1.7 | 0.044 | | 0.067 |
| С | 0.45 | | 0.6 | 0.017 | | 0.023 |
| C2 | 1.23 | | 1.36 | 0.048 | | 0.053 |
| D | 8.95 | | 9.35 | 0.352 | | 0.368 |
| D1 | | 8 | | | 0.315 | |
| E | 10 | | 10.4 | 0.393 | | |
| E1 | | 8.5 | | | 0.334 | |
| G | 4.88 | | 5.28 | 0.192 | | 0.208 |
| L | 15 | | 15.85 | 0.590 | | 0.625 |
| L2 | 1.27 | | 1.4 | 0.050 | | 0.055 |
| L3 | 1.4 | | 1.75 | 0.055 | | 0.068 |
| М | 2.4 | | 3.2 | 0.094 | | 0.126 |
| R | | 0.4 | | | 0.015 | |
| V2 | 00 | | 4º | | | |

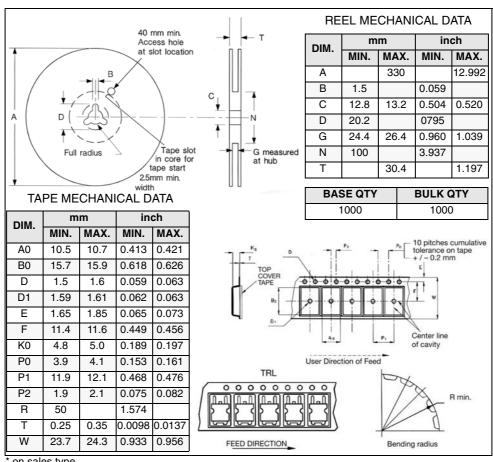


Packaging mechanical data 5

D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT



on sales type

STGB6NC60H Revision history

6 Revision history

Table 7. Revision history

| Date | Revision | Changes |
|-------------|----------|---------------|
| 18-Nov-2005 | 1 | First Release |
| 27-jul-2006 | 2 | New template |

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